DATA SHEET



MOS FIELD EFFECT TRANSISTOR

2SK4070

SWITCHING N-CHANNEL POWER MOS FET

DESCRIPTION

The 2SK4070 is N-channel MOS FET device that features a low gate charge and excellent switching characteristics, and designed for high voltage applications such as switching power supply, AC adapter.

- Low on-state resistance
- $R_{DS(on)} = 11 \Omega MAX. (V_{GS} = 10 V, I_{D} = 0.5 A)$
- Low gate charge
- $Q_G = 5 \text{ nC TYP.}$ ($V_{DD} = 450 \text{ V}$, $V_{GS} = 10 \text{ V}$, $I_D = 1.0 \text{ A}$)
- Gate voltage rating: ±30 V
- Avalanche capability ratings

<R> ORDERING INFORMATION

PART NUMBER	LEAD PLATING	PACKING	PACKAGE		
2SK4070-S15-AY Note	Pure Sn (Tin)	Tube 70 p/tube	TO-251 (MP-3-a) typ. 0.39 g		
2SK4070(1)-S27-AY Note		Tube 75 p/tube	TO-251 (MP-3-b) typ. 0.34 g		
2SK4070-ZK-E1-AY Note		Tape 2500 p/reel	TO 050 (MD 07/4) L + 0.07 +		
2SK4070-ZK-E2-AY Note			TO-252 (MP-3ZK) typ. 0.27 g		

Note Pb-free (This product does not contain Pb in external electrode.)

ABSOLUTE MAXIMUM RATINGS $(T_A = 25^{\circ}C)$

ABSOLUTE MAXIMUM RATINGS (TA - 25 C)									
Drain to Source Voltage (Vss = 0 V)	Voss	600	V						
Gate to Source Voltage (VDS = 0 V)	Vgss	±30	V						
Drain Current (DC) (Tc = 25°C)	I _{D(DC)}	±1.0	Α						
Drain Current (pulse) Note1	I _{D(pulse)}	±4.0	Α						
Total Power Dissipation (Tc = 25°C)	P _{T1}	22	W						
Total Power Dissipation (T _A = 25°C) Note2	P _{T2}	1.0	W						
Channel Temperature	Tch	150	°C						
Storage Temperature	Tstg	-55 to +150	°C						
Single Avalanche Current Note3	las	0.8	Α						
Single Avalanche Energy Note3	Eas	38.4	mJ						

(TO-251)





- **Notes 1.** PW \leq 10 μ s, Duty Cycle \leq 1%
 - 2. Mounted on glass epoxy board of 40 mm × 40 mm × 1.6 mm
 - 3. Starting T_{ch} = 25°C, V_{DD} = 150 V, R_G = 25 Ω , V_{GS} = 20 \rightarrow 0 V

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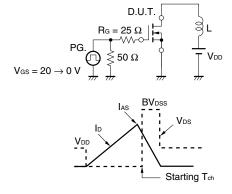
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ELECTRICAL CHARACTERISTICS (TA = 25°C)

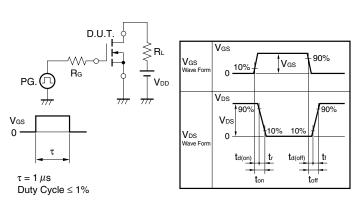
ELLOTRIOAL CHARACTERISTIC	<u> </u>	-	_			
CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Zero Gate Voltage Drain Current	IDSS	V _{DS} = 600 V, V _{GS} = 0 V			100	μΑ
Gate Leakage Current	Igss	V _{GS} = ±30 V, V _{DS} = 0 V			±100	nA
Gate Cut-off Voltage	V _{GS(off)}	V _{DS} = 10 V, I _D = 1 mA	2.5	2.9	3.5	V
Forward Transfer Admittance Note	y _{fs}	V _{DS} = 10 V, I _D = 0.5 A	0.2	0.4		S
Drain to Source On-state Resistance Note	R _{DS(on)}	V _{GS} = 10 V, I _D = 0.5 A		9.2	11	Ω
Input Capacitance	Ciss	V _{DS} = 10 V,		110		pF
Output Capacitance	Coss	V _{GS} = 0 V,		50		pF
Reverse Transfer Capacitance	Crss	f = 1 MHz		11		pF
Turn-on Delay Time	t _{d(on)}	V _{DD} = 150 V, I _D = 0.5 A,		7.5		ns
Rise Time	tr	V _{GS} = 10 V,		6		ns
Turn-off Delay Time	t _{d(off)}	R _G = 10 Ω		11		ns
Fall Time	tr			18		ns
Total Gate Charge	Q _G	V _{DD} = 450 V,		5		nC
Gate to Source Charge	Qgs	V _{GS} = 10 V,		1		nC
Gate to Drain Charge	Q _{GD}	I _D = 1.0 A		2.8		nC
Body Diode Forward Voltage Note	V _{F(S-D)}	I _F = 1.0 A, V _{GS} = 0 V		0.86	1.5	V
Reverse Recovery Time	trr	I _F = 1.0 A, V _{GS} = 0 V,		135		ns
Reverse Recovery Charge	Qrr	di/dt = 100 A/μs		285		nC

Note Pulsed

TEST CIRCUIT 1 AVALANCHE CAPABILITY

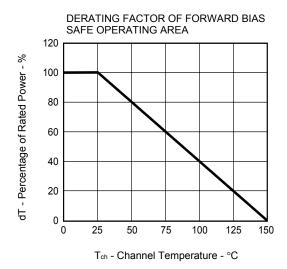


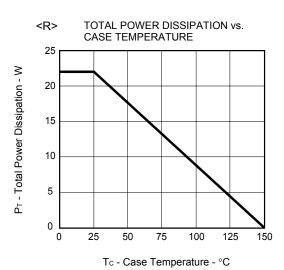
TEST CIRCUIT 2 SWITCHING TIME

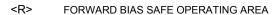


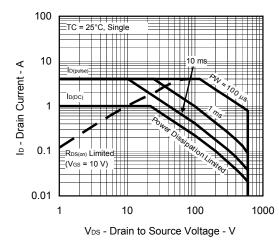
TEST CIRCUIT 3 GATE CHARGE

TYPICAL CHARACTERISTICS (TA = 25°C)

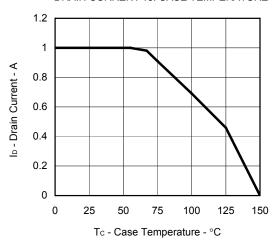




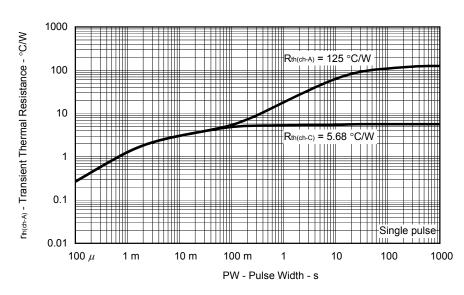


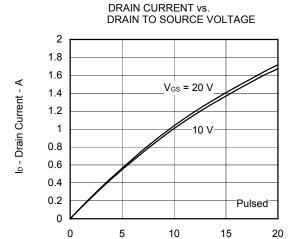






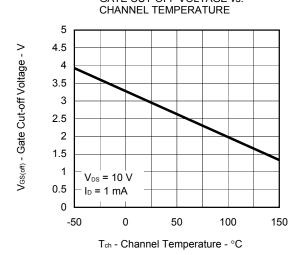
<R> TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH



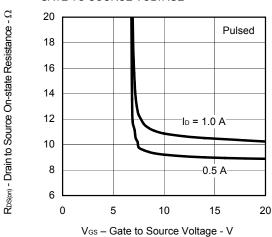




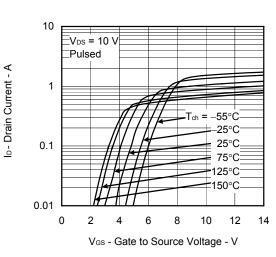
V_{DS} - Drain to Source Voltage - V



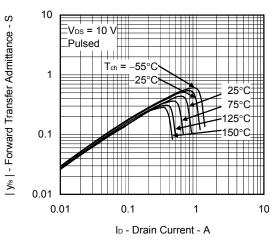
DRAIN TO SOURCE ON-STATE RESISTANCE vs. GATE TO SOURCE VOLTAGE



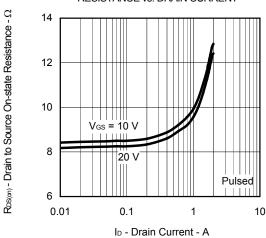
FORWARD TRANSFER CHARACTERISTICS

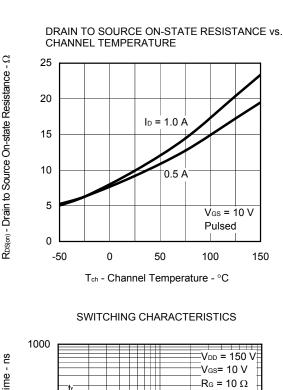


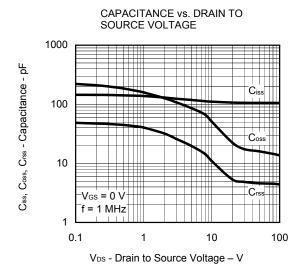
FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT

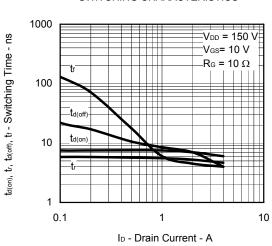


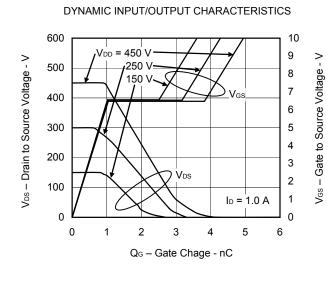
DRAIN TO SOURCE ON-STATE RESISTANCE vs. DRAIN CURRENT

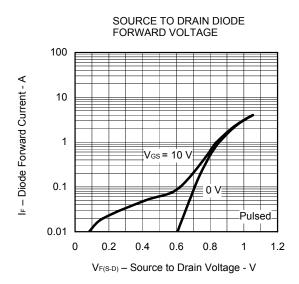


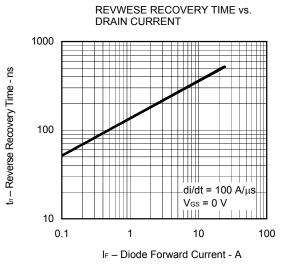




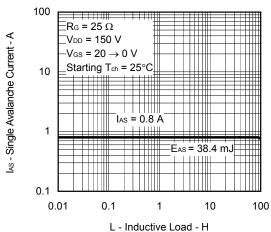




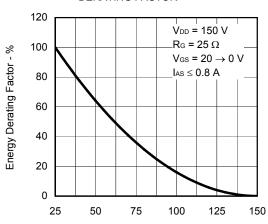




SINGLE AVALANCHE CURRENT vs. INDUCTIVE LOAD

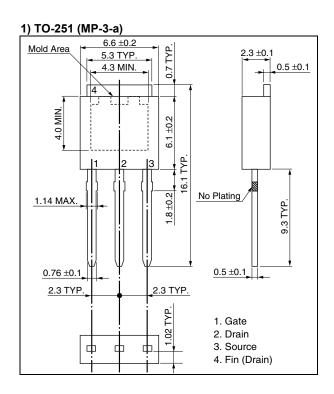


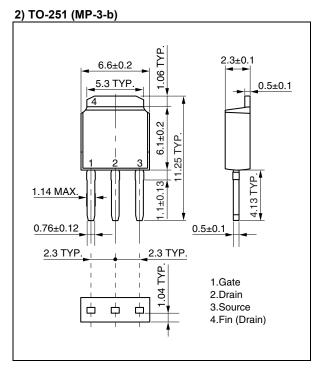
SINGLE AVALANCHE ENERGY DERATING FACTOR



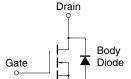
Starting T_{ch} - Starting Channel Temperature - $^{\circ}$ C

<R> PACKAGE DRAWINGS (Unit: mm)





3) TO-252 (MP-3ZK) 1.0 TYP. 2.3±0.1 6.5±0.2 0.5±0.1 5.1 TYP. 4.3 MIN No Plating 10.4 MAX. (9.8 TYP.) 4.0 MIN. 6.1±0.2 0.51 MIN 0.8 No Plating 1.14 MAX 0.76±0.12 0 to 0.25 2.3 0.5±0.1 1. Gate 2. Drain 3. Source 4. Fin (Drain)



Source

EQUIVALENT CIRCUIT

Remark Strong electric field, when exposed to this device, can cause destruction of the gate oxide and ultimately degrade the device operation. Steps must be taken to stop generation of static electricity as much as possible, and quickly dissipate it once, when it has occurred.

NEC 2SK4070

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